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3/25/03

PATENT  
Customer No. 22,852  
Attorney Docket No. 06484.0073

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
)  
Shi-Tron LIN ) Group Art Unit: 2822  
)  
Serial No.: 09/740,017 ) Examiner: S. Meier  
)  
Filed: December 20, 2000 )  
)  
For: TRANSISTOR STRUCTURE FOR )  
ELECTROSTATIC DISCHARGE )  
PROTECTION CIRCUIT )

Commissioner for Patents  
Washington, DC 20231

Sir:  
00000122 09740017

03/21/2003 JBALINAN

01 FC:1201  
02 FC:1202

84.00 OP  
54.00 OP

AMENDMENT

RECEIVED  
MAR 24 2003  
TECHNOLOGY CENTER 2800

In reply to the Office Action dated September 30, 2002, the period for response to which has been extended through March 30, 2003, by a Petition for Extension of Time of three months and requisite fee payment filed herewith, please amend the application as follows:

IN THE SPECIFICATION:

Please replace the paragraph beginning at page 12, line 6, with the following paragraph:

Fig. 8 illustrates an ESD device 600 constructed according to a fourth embodiment of the present invention. With reference to Fig. 8, device 600 includes a single island 602 in and along drain region 412 and adjacent gate 414, and a single island 602 in and along drain region 412 and adjacent gate 416. The left end of island

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01 FC:1253

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